Filing Date: 12-Jul-2006								
Application Number:	10585744							
Filing Date:	12-Jul-2006							
Title of Invention:	N-Type Group III Nitride Semiconductor Layered Structure							
First Named Inventor/Applicant Name:	Akira Bandoh							
Filer:	Abraham Jacob Rosner/Terri Coates							
Attorney Docket Number:	Q81505							
Filed as Large Entity								
U.S. National Stage under 35 USC 371 Filing	Fee	s						
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)			
Basic Filing:								
Pages:								
Claims:								
Miscellaneous-Filing:								
Petition:								
Patent-Appeals-and-Interference:								
Post-Allowance-and-Post-Issuance:								
Extension-of-Time:								
Extension - 2 months with \$130 paid		1252	1	360	360			

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Request for continued examination	1801	1	810	810
	Tot	1170		